

Stark-Wannier States in Nanostructures

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We study the effects of a longitudinal-external-electric field on the electronic properties of a multiple open-quantum-dot structure. The transmission coefficients between two quasi-two dimensional reservoirs through the structure are calculated. This structure presents the formation of two different gaps, one associated with the periodicity of the structure imposed upon the 1D mode and the other associated to the destructive interference between the 1D band and the quantum-dot states band. The electric field localizes the levels into Wannier-Stark states. The interplay between the 1D mode and the Stark ladder formed by the dot levels is discussed.

I. Introduction

Mesoscopic systems have been intensively studied in the recent years^[1]. With the improvement of nano-scale fabrication techniques, it has been possible to design a whole new kind of structures based on the high-mobility two-dimensional (2D) electron gas formed in GaAs-(Ga,Al)As heterojunctions. The physics behind these systems is based on the lateral confinement which binds the carriers in one or two additional dimensions besides the epitaxial one. Recently, the interplay between one- and zero-dimensional levels has been considered. Particularly, an open-quantum-dot superlattice was built and transmission gaps were observed^[2]. The existence of carrier confinement in open cavities is well known since the works by Schult et al^[3], van der Marel^[4] and Peeters^[5]. Ulloa et al.^[6] discussed the effects of a periodic quantum-dot structure superimposed on a one-dimensional channel. Brum^[7] discussed the effects of the interplay between the cavity confined states and the superlattice states. More recently, other structures based on the same principles have been considered^[8,9]. The effects of a longitudinal-external-electric field, F , in a single constriction and quantum chains, have been studied by Castaño et. al.^[10]. Their emphasis was on the nonlinear transport characteristics in these nanostructures.

An electric field superimposed on a periodic po-

tential leads to the replacement of the band structure by a ladder of spatially localized states, Wannier-Stark states (WSS), equally spaced in energy by eFd , where d is the periodicity of the structure^[11]. Their observation in bulk crystals has been a matter of controversy^[12]. With the advent of the artificial semiconductor structures, it has been possible to observe these states^[13] and recently, they have been observed in one-dimensional semiconductor superlattices^[14,15]. The coupling among WSS originated from different subbands has also been considered^[16,17].

In this work, we discuss the effects of an external electric field applied along an asymmetric-multiple-open-quantum-dot structure (AMOQDS) and our main interest is on their electronic properties. They will be probed by the transmission coefficient through the structure enclosed by two quasi-two-dimensional reservoirs. Our structure is similar to the one discussed previously by one of us^[7] and the one studied by Kouwenhoven et al.^[2]. A laterally patterned GaAs/(Ga,Al)As heterojunction is considered. We assume a strong confinement along the z -direction so that the system is in the Electric Quantum Limit with respect to quantization of motion in this direction. The lateral confinement is sketched in Fig. 1. Two structures are studied: One with a single quantum dot and the other with three quantum dots. We perform a multi-mode transmission calculation following the same method as in

previous work^[7,12]. We approximate the electric field effects by considering only the potential drop from one layer respective to the other. Inside each layer, a flat band is assumed (see Fig. 2). Our calculations for a large number of dots have shown that three dots are already enough to reflect the main superlattice effects. Basically, the structures are formed by periodic indentations superimposed on one side of a one-dimensional (1D) channel. The carriers are assumed to be ballistic. They are linked to the two wide regions which behave as quasi-two dimensional reservoirs. The indentations give origin to a zero-dimensional confinement potential. At least one zero-dimensional state is energetically below the first 1D mode. The higher dot states will then be resonances in the 1D modes.

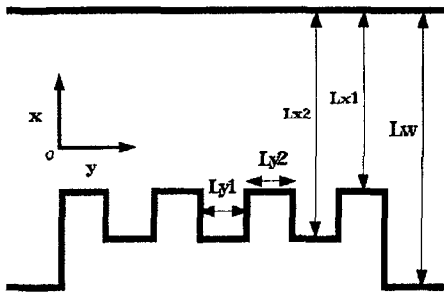


Figure 1: Top view of the potential of the asymmetric-open-quantum-dot structure.

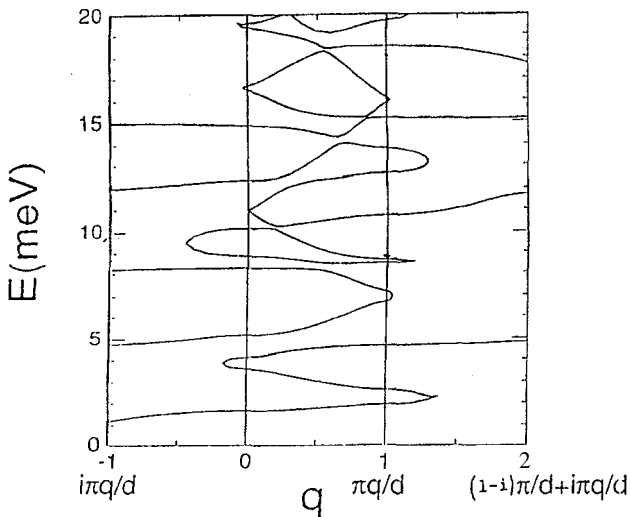


Figure 2: Scheme of the energy profiles of the structure of Fig. 1 under a longitudinal electric field.

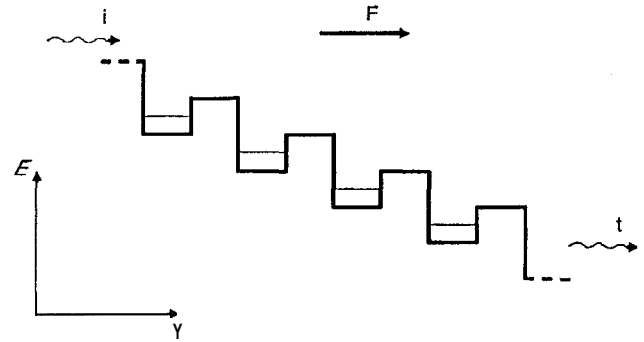


Figure 3: Miniband dispersion for the structure of Fig. 1.

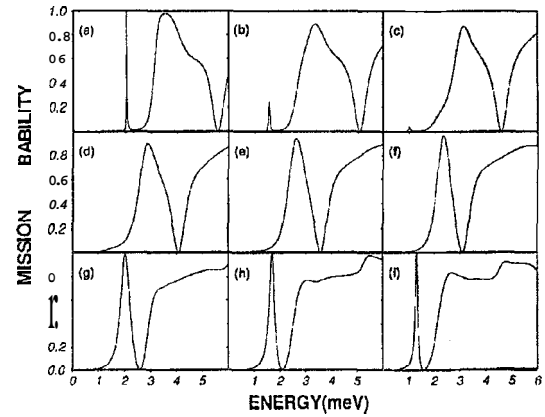


Figure 4: Transmission probabilities for an one-asymmetric-open-quantum-dot structure as a function of the incoming energy. $L_w = 4000 \text{ \AA}$, $L_{y1} = L_{y2} = 500 \text{ \AA}$, $L_{x1} = 500 \text{ \AA}$, $L_{x2} = 800 \text{ \AA}$. a) $F = 0 \text{ kV/cm}$; b) $F = 0.067 \text{ kV/cm}$; c) $F = 0.134 \text{ kV/cm}$; d) $F = 0.2 \text{ kV/cm}$; e) $F = 0.267 \text{ kV/cm}$; f) $F = 0.334 \text{ kV/cm}$; g) $F = 0.4 \text{ kV/cm}$; h) $F = 0.467 \text{ kV/cm}$ and i) $F = 0.534 \text{ kV/cm}$.

Basically, the one-dot structure can be viewed as a wide 1D band, the 1D mode, with a ground-OD state at energy below the 1D band and excited OD states degenerated and coupled to the 1D band. The former gives a peak in the transmission, as it is expected in resonant tunneling. The later states give origin to a situation typical of Fano resonances^[18] with a dip associated to the peak due to the localized state. In the transmission coefficients, however, whenever the 1D mode is fully open for transmission, the peak associated with the OD state disappears and only the dip is present.^[8] This is associated with the strong anti-resonance present in the transmission coefficients.

For the three-dots structure, in spite of the limited number of dots, the results show aspects of a finite superlattice. The wide 1D band folds into the new

Brillouin zone, introduced by the periodicity. The OD states give origin to narrow bands. The folded bands are still wide in comparison to the bands formed by the OD states. These two sets of bands are intrinsically coupled. When the narrow band is degenerated with the wide band, they actually anti-cross. As a consequence of the anti-crossing, a gap in the band structure is opened and the transmission falls to zero in this region. In our case, the anti-crossing coming from the coupling is larger than the band width of the narrow bands. Therefore, the transmission does not reach values above one. Additionally to the transmission gaps due to the anti-crossings, we observe the gaps associated to the periodicity imposed upon the 1D mode, as it should be expected.

This is well illustrated in Fig. 3, where the mini-band dispersion is plotted. The imaginary- q part of the dispersion is also described. The two gaps show a qualitative difference in respect to the imaginary- q dispersion. The bands originated from the folding of the 1D band are connected at imaginary values of q . The bands separated by the anti-crossing due to the coupling of the narrow and wide bands do not connect at finite values of q . This is expected since the gap is originated from the anti-crossing between the localized and extended states.

The transmission probabilities, in the absence of electric field, are shown in Figs. 4 (a) and 6 (a) for the one and three dots structures. At energies below the first-1D mode, we observe the peaks with unitary transmission associated to the ground-OD levels. At energies above the first-1D mode, transmission gaps are superimposed on the step quantization of the transmission. The character of the gaps is well illustrated with the wave-functions. Fig. 5(a) shows the wave-function probabilities for a one-open-quantum-dot for an energy at the second transmission maximum in the absence of electric field. Fig. 7(a) shows the wave-function prob-

ability for a three-open-quantum-dot structure, for an energy at the third peak of the first transmission band maximum, in the absence of the electric field. Fig. 5(a) shows maxima of probability of finding the electron at the narrow constrictions characterizing the states as 1D mode-like. On the other hand, the third peak of the first transmission band maximum, Fig. 7(a), shows the maximum of the wave-function probability at the wide constriction, i.e., at the quantum dots.

Figs. 4 (a-i) shows the transmission probability for the one-dot case as a function of the electron incoming energy for several values of electric field. At weak electric fields, we clearly observe a linear shift in energy of the first transmission peak. This peak is associated with the tunneling through the fundamental quantum dot state below the first 1D mode. The anti-resonance gap, associated to the second dot state, shows an identical shift, as it is expected. For the same range of electric field, the transmission maxima fall to values lower than one. This is a consequence of the break of symmetry in the barriers through which the electron has to tunnel^[19]. As the electric field increases, the first peak is suppressed since it shifted to energy values below the emitter minimum.

At intermediate fields, we observe the evolution of the transmission band towards a sharp peak. Originally, this band is associated with the first 1D mode. With the electric field, the first 1D mode hybridizes with the dot state giving origin to a sharp transmission. Again, the level is an extended state and the transmission reaches the unitary value. This is illustrated in Figs. 5(a) and 5(b) where the wave-function probability for the second transmission maximum is plotted for zero electric field and for $F=0.53$ kV/cm. We clearly observe its evolution from a 1D mode toward a 1D-OD hybrid state.

For the three dots structure, the electric-field effects

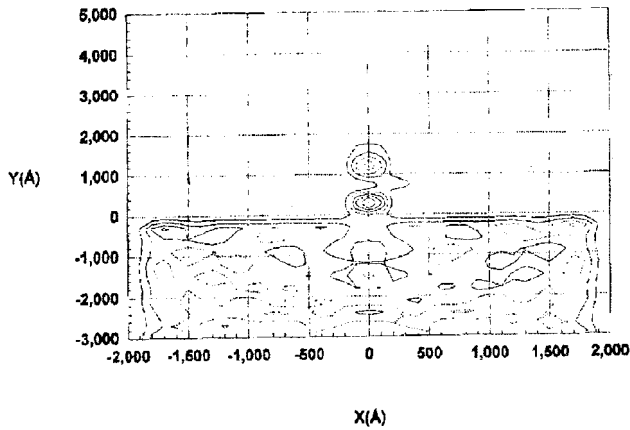


Figure 5a: upper panel

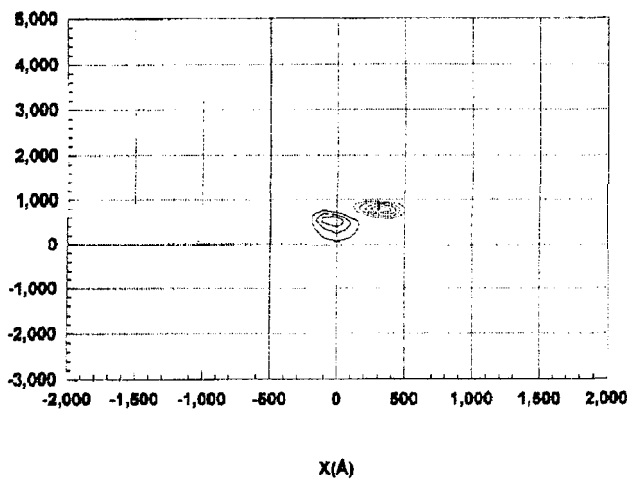


Figure 5b: upper panel

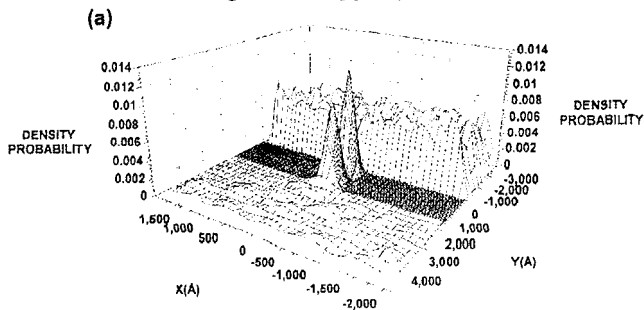


Figure 5a: lower panel

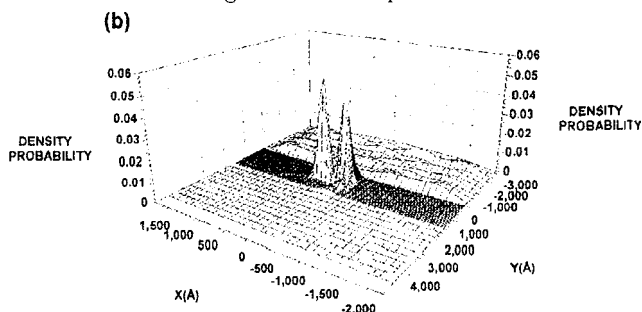


Figure 5b: lower panel

Figure 5: Wave-function probabilities (upper panel: 3D plot; lower panel: 2D projection) for the same structure as Figure 2 for a) $F=0$ kV/cm, $E = 3.6$ meV; b) $F = 0.534$ kV/cm and $E = 1.3$ meV.

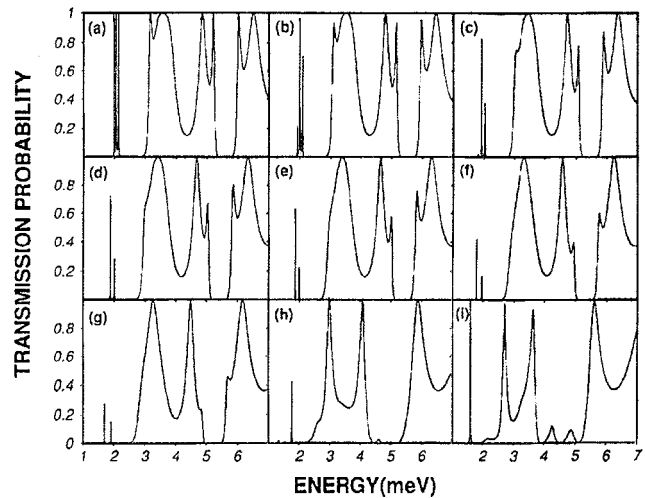


Figure 6: Transmission probabilities for a three-asymmetric-open-quantum dot structure as a function of the incoming energy. a) $F = 0$ kV/cm; b) $F = 0.004$ kV/cm; c) $F = 0.008$ kV/cm; d) $F = 0.01$ kV/cm; e) $F = 0.012$ kV/cm; f) $F = 0.016$ kV/cm; g) $F = 0.02$ kV/cm; h) $F = 0.04$ kV/cm and i) $F = 0.06$ kV/cm. The other parameters are the same as in Fig. 2.

can be analyzed in terms of the different kinds of bands. The continuous band is replaced by a ladder of bound levels evenly spaced by eFd . The localization of the states goes with $eFd \ll \Delta$, where Δ is the band width. As we increase the electric field, the narrow band break immediately into the Stark ladder. The energy difference among the levels increases linearly with the field and the wave-function localizes in the dot. On the other hand, for the wide bands, at sizable electric fields, the states remain extended over a large number of wells. The description of a continuous band, or an open 1D mode, is still valid. The coupling of these two bands gives a new behavior in the Stark ladder effects.

Fig. 6 (a-i) shows the three-dots' structure transmission probability as a function of the electron incoming energy for several electric fields. The first series of maxima in the transmission are associated to the narrow band formed by the confined-fundamental-dot states. The second transmission band is associated with the 1D mode. After that, we observe a strong reduction in the transmission probability which is related to the gap formed by the periodicity of the structure. The next gap is due to the anti-crossing between the 1D

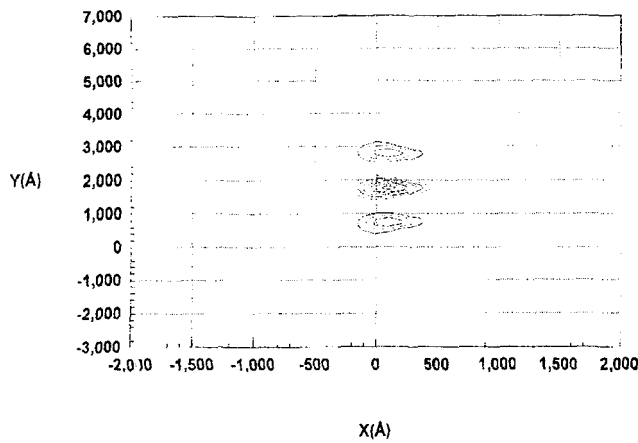


Figure 7a: lower panel

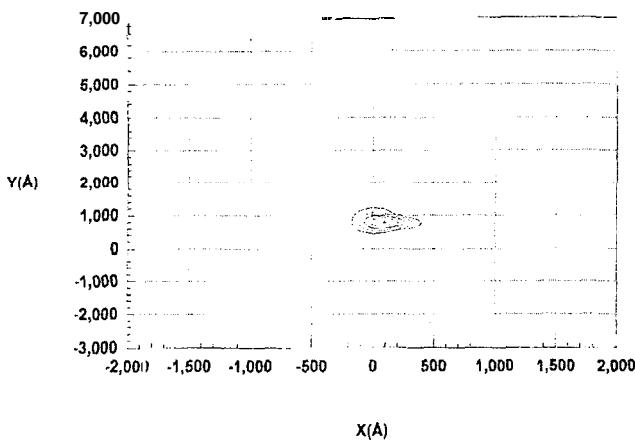


Figure 7b: lower panel

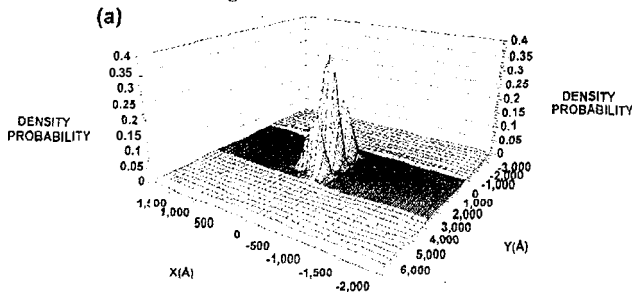


Figure 7a: upper panel

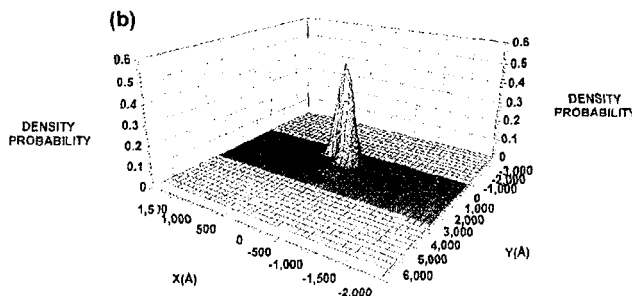


Figure 7b: upper panel

Figure 7: Wave-function probabilities (upper panel: 3D plot; lower panel: 2D projection) for the same structure as Fig. 6 for a) $F = 0$ kV/cm, $E = 2.1$ meV, b) $F = 0.06$ kV/cm and $E = 1.6$ meV.

mode and the dot bands. This gap is strongly marked even for a small number of periods^[7] as a consequence of the behavior of band dispersion at the anti-crossing for imaginary values of q .

At weak electric fields, the first band shows a similar behavior as the single dot case: a linear energy shift is observed accompanied by the fall of the transmission probability. At higher electric fields ($F > 0.02$ kV/cm) the transmission peaks again for a single level, reaching the unitary value for the level associated to the first dot. The other levels have practically disappeared. This is easily understood in terms of the symmetry of the effective barriers through which the state has to tunnel. At very weak fields, the degeneracy among the dot states is already broken, the state which localizes in the first dot sees an effective barrier on the left which is narrower than the effective barrier on the right. The latter is formed by three narrow constrictions and two wide constrictions while the former is just one narrow constriction. As a consequence of the asymmetry, the transmission peak is below one^[19]. As the field increases, the right effective barrier decreases. At a precise value of the electric field, the two effective barriers are equal and we have a symmetric tunneling, recovering the unitary transmission. As we further increase the field, the right effective barrier becomes narrower than the left one and the tunneling is again through asymmetric effective barriers. The transmission peak falls again below one.

The other bands have a different behavior as a consequence of the wide band width. The states remain delocalized along the whole structure for most of the fields considered here. As a consequence, the one 1D mode is fully open for transmission and its value remains equal to one. Only at higher fields, as the states start to localize, the transmission begins to fall to lower values. This behavior gives a measure of the localization of the wave-function in the structure. For larger structures, that is, a larger number of periods, the transmission falls to values below one for lower values of the elec-

tric field. This is expected since to have the 1D mode opened means that the wave-function has to be delocalized along a larger number of periods.

The narrow band, which is degenerated with the 1D mode, breaks into the Stark ladder for very weak electric fields. For a range of values of the electric field, we have the coexistence of WSS coupled to a 1D band. As for the zero field case, the localized states open an anti-resonance gap. If the energy separation among the WSS is smaller than the coupling among them and the extended state, the transmission remains equal to zero and the gap increases slightly with the electric field. However, when the energy separation among the WSS is of the order of the coupling, then some transmission is possible between the states. This is well illustrated in Figs. 6 (a-i) by the evolution of the transmission with the electric field. The transmission correspondent to the 1D band remains equal to one except for the last value of electric field considered. At the same time, the anti-resonance gap is always present, increasing with the field up to values for which the Stark ladder splitting is of the order of the coupling and the gap is destroyed. This happens for fields around 0.06 kV/cm which corresponds to a splitting of 0.6 meV. This value is of the order of the coupling as it can be estimated from Fig. 4 (a) by the width at half height of the anti-resonance gap.

A direct observation of the above effects depends on several additional effects. Conductance measurements have been one of the most powerful experimental tools to probe similar effects^[1,2]. However, some aspects remain to be cleared: charge effects, such as Coulomb blockade, may hamper their observation for the state-of-art of the mesoscopic systems. Another difficulty is in the connection among transmission probabilities and conductance measurements, particularly in the presence of nonlinear effects. A complete solution of the transport problem in these systems is beyond the scope of this work. Nevertheless, we believe that the effects discussed here should be reflected in the electronic prop-

erties of actual systems and should be considered whenever confined cavity states are coupled to 1D modes.

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